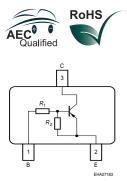
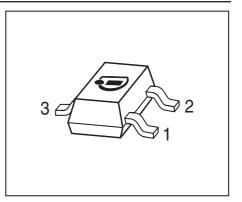


PNP Silicon Digital Transistor

- Built in bias resistor (R_1 = 4.7 k Ω , R_2 = 4.7 k Ω)
- Pb-free (RoHS compliant) package
- Qualified according AEC Q101





Туре	Marking	Pin Configuration			Package
BCR562	XUs	1=B	2=E	3=C	SOT23

Maximum Ratings

Junction - soldering point¹⁾

Parameter	Symbol	Value	Unit
Collector-emitter voltage	V _{CEO}	50	V
Collector-base voltage	V _{CBO}	50	
Input forward voltage	V _{i(fwd)}	30	
Input reverse voltage	V _{i(rev)}	10	
Collector current	I _C	500	mA
Total power dissipation-	P _{tot}	330	mW
<i>T</i> _S ≤ 79 °C			
Junction temperature	Ti	150	°C
Storage temperature	T _{stg}	-65 150	
Thermal Resistance			
Parameter	Symbol	Value	Unit

¹For calculation of R_{thJA} please refer to Application Note AN077 (Thermal Resistance Calculation)

K/W

 ≤ 215

R_{thJS}



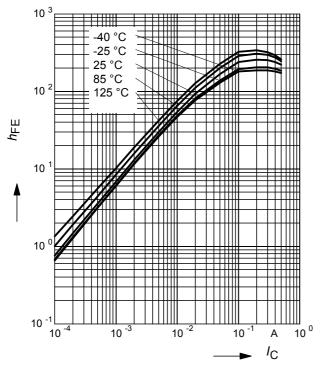
Parameter	Symbol	Values			Unit
		min.	typ.	max.	
DC Characteristics					
Collector-emitter breakdown voltage	V _{(BR)CEO}	50	-	-	V
<i>I</i> _C = 100 μA, <i>I</i> _B = 0					
Collector-base breakdown voltage	V _{(BR)CBO}	50	-	-	
$I_{\rm C}$ = 10 µA, $I_{\rm E}$ = 0					
Collector-base cutoff current	I _{CBO}	-	-	100	nA
$V_{\rm CB}$ = 50 V, $I_{\rm E}$ = 0					
Emitter-base cutoff current	I _{EBO}	-	-	1.61	mA
$V_{\rm EB}$ = 10 V, $I_{\rm C}$ = 0					
DC current gain-	h _{FE}	60	-	-	-
<i>I</i> _C = 50 mA, <i>V</i> _{CE} = 5 V					
Collector-emitter saturation voltage1)	V _{CEsat}	-	-	0.3	V
<i>I</i> _C = 50 mA, <i>I</i> _B = 2.5 mA					
Input off voltage	V _{i(off)}	0.6	-	1.5	
<i>I</i> _C = 100 μA, <i>V</i> _{CE} = 5 V					
Input on voltage	V _{i(on)}	1	-	2.2]
<i>I</i> _C = 10 mA, <i>V</i> _{CE} = 0.3 V					
Input resistor	R ₁	3.2	4.7	6.2	kΩ
Resistor ratio	R ₁ /R ₂	0.9	1	1.1	-
AC Characteristics	· · · · · · · · · · · · · · · · · · ·				
Transition frequency	f _T	-	150	-	MHz
$I_{\rm C}$ = 50 mA, $V_{\rm CE}$ = 5 V, f = 100 MHz					
	· · · · · · · · · · · · · · · · · · ·				•

Electrical Characteristics at $T_{\Delta} = 25^{\circ}$ C, unless otherwise specified

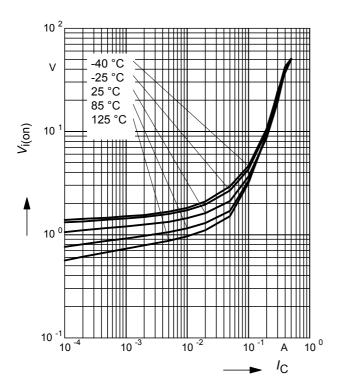
¹Pulse test: t < 300 μ s; D < 2%



DC current gain $h_{FE} = f(I_C)$ $V_{CE} = 5 V$ (common emitter configuration)

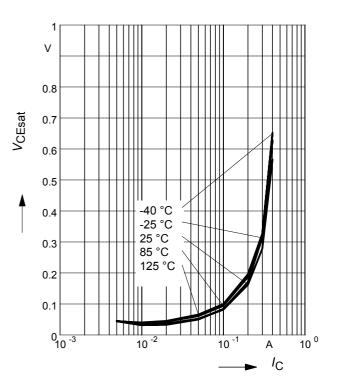


Input on Voltage $V_{i(on)} = f(I_C)$ $V_{CE} = 0.3V$ (common emitter configuration)

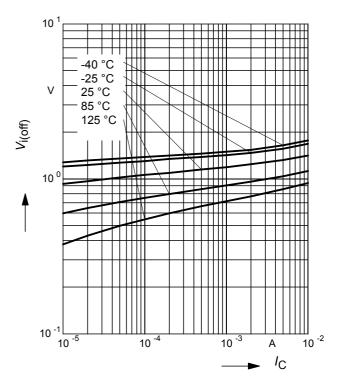


Collector-emitter saturation voltage

 $V_{\text{CEsat}} = f(I_{\text{C}}), h_{\text{FE}} = 20$



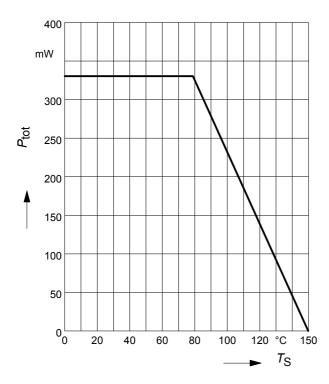
Input off voltage $V_{i(off)} = f(I_C)$ $V_{CE} = 5V$ (common emitter configuration)





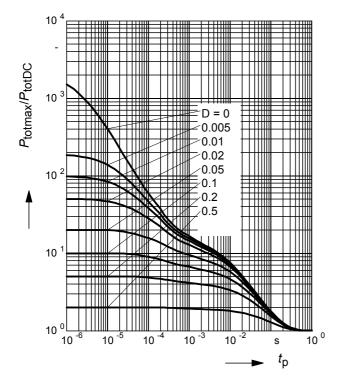
Total power dissipation $P_{tot} = f(T_S)$

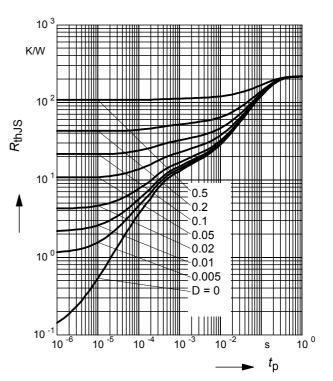
Permissible Pulse Load $R_{\text{thJS}} = f(t_p)$



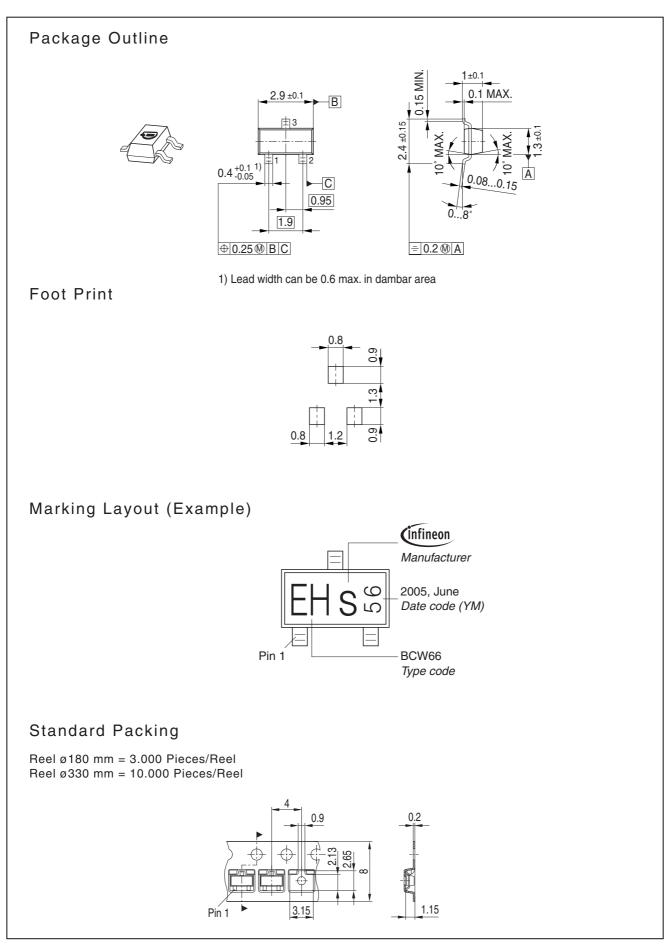
Permissible Pulse Load

 $P_{\text{totmax}}/P_{\text{totDC}} = f(t_{p})$











Edition 2009-11-16

Published by Infineon Technologies AG 81726 Munich, Germany

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